# 

## PJQ4526P

## 30V N-Channel Enhancement Mode MOSFET

Voltage

Current 62 A

#### Features

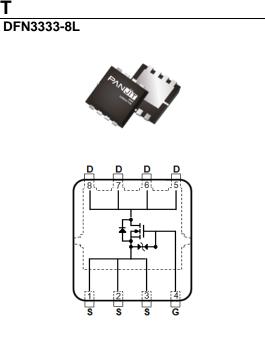
•  $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@10A < 5.5m\Omega$ 

30 V

- Rds(on), Vgs@4.5V, Id@6A<8.3m $\Omega$
- Excellent FOM
- Logic Level Drive
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams



#### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT		
Drain-Source Voltage		V <sub>DS</sub>	30		
Gate-Source Voltage		V <sub>GS</sub>	±20	V	
Continuous Drain Current <sup>(Note 3)</sup>	Tc=25°C		62		
	Tc=100°C	I <sub>D</sub>	39	Α	
Pulsed Drain Current <sup>(Note 1)</sup>	T <sub>C</sub> =25°C	I <sub>DM</sub>	248		
Power Dissipation	T <sub>C</sub> =25°C	<b>D</b> -	31.3	14/	
	Tc=100°C	PD	12.5	W	
Continuous Drain Current <sup>(Note 4)</sup>	T <sub>A</sub> =25°C		16		
	T <sub>A</sub> =70°C	I <sub>D</sub>	12.7	Α	
Power Dissipation	T <sub>A</sub> =25°C	PD	2.1	W	
	T <sub>A</sub> =70°C	PD	1.3	vv	
Single Pulse Avalanche Energy <sup>(Note 5)</sup>		Eas	28	mJ	
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	°C	
Thermal Resistance <sup>(Note 4)</sup>	Junction to Case	R <sub>θJC</sub>	4	°C/W	
	Junction to Ambient	R <sub>0JA</sub>	60	C/W	



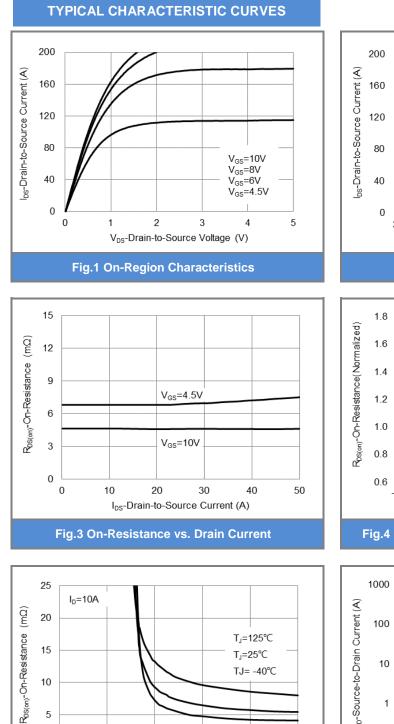
#### Electrical Characteristics (TA=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static				1			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	/ <sub>DSS</sub> V <sub>GS</sub> =0V, I <sub>D</sub> =250uA 30		-	-		
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1.3	1.7	2.5	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =10A	-	4.6	5.5	mΩ	
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =6A	-	6.4	8.3		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V	-	-	±1	uA	
		V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	-	-	±10		
Gate-Source Leakage Current	IGSS	V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V	-	-	±1	uA	
Dynamic <sup>(Note 6)</sup>						-	
Total Gate Charge	Qg		-	15	-	nC	
Gate-Source Charge	Qgs	V <sub>DS</sub> =24V, I <sub>D</sub> =10A, V <sub>GS</sub> =10V <sup>(Note 2,3)</sup>	-	3.4	-		
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V <sup>(Note 2,3)</sup>	-	2.1	-		
Input Capacitance	Ciss		-	923	-	pF	
Output Capacitance	Coss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V,	-	442	-		
Reverse Transfer Capacitance	Crss	f=1MHz	-	36	-		
Gate resistance	Rg	f=1MHz	-	1.6	-	Ω	
Turn-On Delay Time	td <sub>(on)</sub>		-	13	-	ns	
Turn-On Rise Time	tr	V <sub>DS</sub> =24V, I <sub>D</sub> =10A,	-	8	-		
Turn-Off Delay Time	td(off)	V <sub>GS</sub> =10V, R <sub>G</sub> =3Ω (Note 2,3)	-	24	-		
Turn-Off Fall Time	tf	(11018 2,3)	-	23	-		
Drain-Source Diode	•	•	•		•		
Diode Forward Current	Is	T- 250C	-	-	62	A	
Pulsed Diode Forward Current	I <sub>SM</sub>	Tc=25°C	-	-	248		
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =20A, V <sub>GS</sub> =0V	-	0.8	1.1	V	
Reverse Recovery Time	Trr	V <sub>GS</sub> =0V, I <sub>S</sub> =20A	-	27	-	ns	
Reverse Recovery Charge	Qrr	dls/dt=100A/us <sup>(Note 2,3)</sup>	-	13	-	nC	

NOTES :

- 1. Pulse width100us, Duty cycle<2%.</td>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an  $R_{\theta JC}=4^{\circ}C/W$ .
- 4.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 5. 6. The test condition is L=0.5mH,  $I_{AS}$ =11A,  $V_{DD}$ =30V,  $V_{GS}$ =10V, Starting TJ=25°C. the chip is about to carry  $I_{AS}$ ≈21A.
- 6. Guaranteed by design, not subject to production testing.



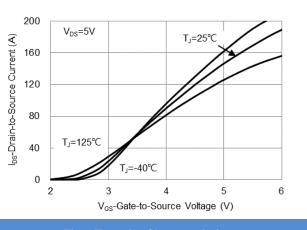


TJ= -40℃

8

10

6





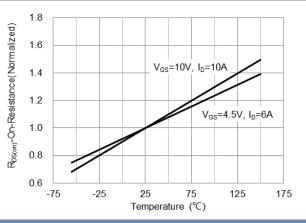
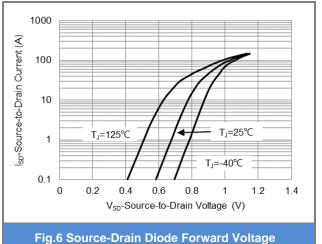


Fig.4 On-Resistance vs. Junction temperature



10

5

0

0

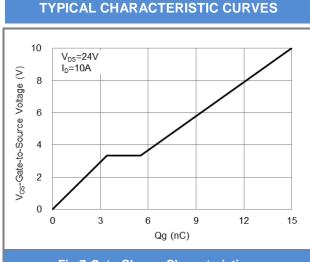
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Fig.5 On-Resistance Variation with V<sub>GS</sub>

V<sub>GS</sub>-Gate-to-Source Voltage (V)







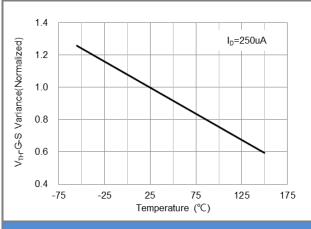
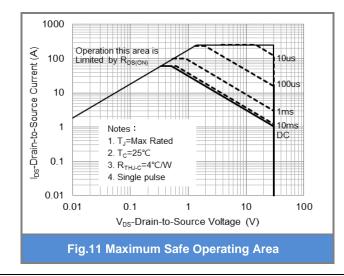
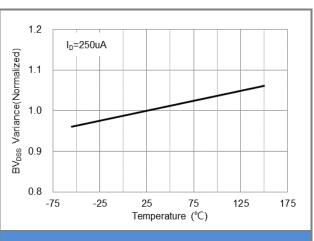


Fig.9 Threshold Voltage Variation with Temperature







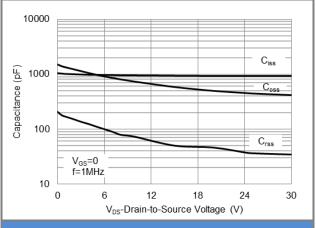
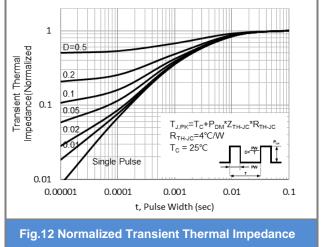


Fig.10 Capacitance vs. Drain-Source Voltage

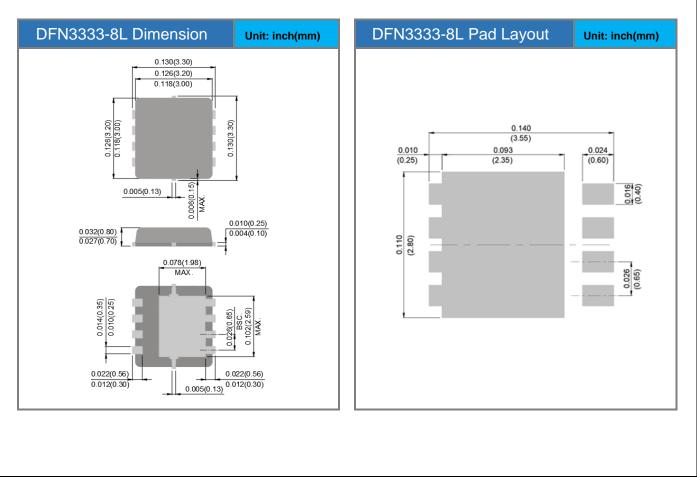




#### **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking	
PJQ4526P	DFN3333-8L	5K pcs / 13" reel	4526	

#### Packaging Information & Mounting Pad Layout





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